



Description

The XPX7410RX uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

- High density cell design for ultra low R_{dson}
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

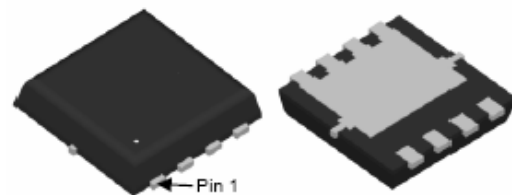
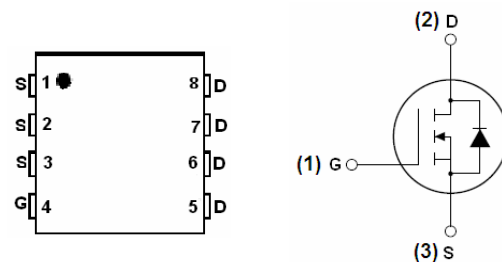
Application

- Secondary side synchronous rectifier
- High side switch in POL DC/DC converter

$V_{DS} = 30V, I_D = 23A$

$R_{DS(ON)} = 16m\Omega @ V_{GS} = 10V$

$R_{DS(ON)} = 21m\Omega @ V_{GS} = 4.5V$



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
XPX7410ARX	XPX7410RX	DFN 3x3-8	-	-	5000

Absolute Maximum Ratings ($T_C = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous	I_D	23	A
Pulsed Drain Current	I_{DM}	28	A
Maximum Power Dissipation	P_D	18	W
Derating factor		0.28	W/ $^\circ C$
Single pulse avalanche energy ^(Note 5)	E_{AS}	150	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 150	$^\circ C$
Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{\theta JC}$	2.5	$^\circ C/W$

Electrical Characteristics ($T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

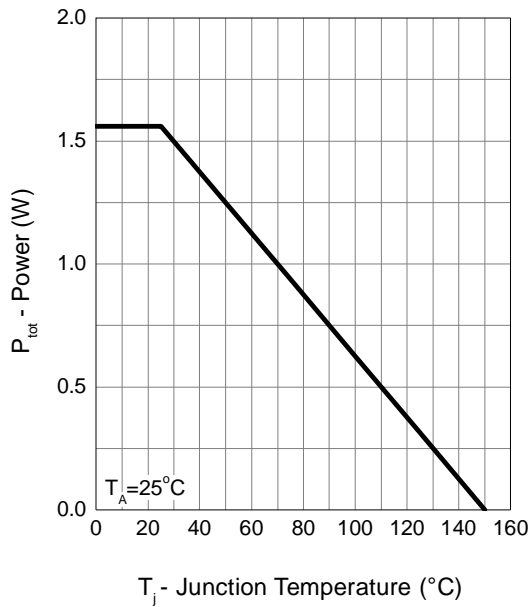
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_{DS}=250\mu A$	30	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=24V, V_{GS}=0V$	-	-	1	μA
		$T_J=85^\circ C$	-	-	30	
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_{DS}=250\mu A$	1.0	1.8	2.5	V
I_{GSS}	Gate Leakage Current	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
$R_{DS(ON)}^d$	Drain-Source On-state Resistance	$V_{GS}=10V, I_{DS}=8A$	-	16	21	m Ω
		$T_J=125^\circ C$	-	25.5	-	
		$V_{GS}=4.5V, I_{DS}=5A$	-	21	26	
Diode Characteristics						
V_{SD}^d	Diode Forward Voltage	$I_{SD}=1A, V_{GS}=0V$	-	0.75	1.1	V
t_{rr}^e	Reverse Recovery Time	$I_{SD}=8A, dI_{SD}/dt=100A/\mu s$	-	12	-	ns
t_a	Charge Time		-	6.2	-	
t_b	Discharge Time		-	5.8	-	
Q_{rr}^e	Reverse Recovery Charge		-	3.7	-	
Dynamic Characteristics^e						
R_G	Gate Resistance	$V_{GS}=0V, V_{DS}=0V, F=1MHz$	1	1.5	3	Ω
C_{ISS}	Input Capacitance	$V_{GS}=0V, V_{DS}=15V, \text{Frequency}=1.0MHz$	300	415	550	pF
C_{OSS}	Output Capacitance		50	70	100	
C_{RSS}	Reverse Transfer Capacitance		30	40	60	
$t_{d(ON)}$	Turn-on Delay Time	$V_{DD}=15V, R_L=15\Omega, I_{DS}=1A, V_{GEN}=10V, R_G=6\Omega$	-	5.5	9	ns
t_r	Turn-on Rise Time		-	9	18	
$t_{d(OFF)}$	Turn-off Delay Time		-	14	25	
t_f	Turn-off Fall Time		-	3.6	7	
Gate Charge Characteristics^e						
Q_g	Total Gate Charge	$V_{DS}=15V, V_{GS}=4.5V, I_{DS}=8A$	-	3.8	5.5	nC
Q_g	Total Gate Charge	$V_{DS}=15V, V_{GS}=10V, I_{DS}=8A$	-	8	13	
Q_{gth}	Threshold Gate Charge		-	0.4	0.7	
Q_{gs}	Gate-Source Charge		-	1.1	1.8	
Q_{gd}	Gate-Drain Charge		-	1.6	2.1	

Note d : Pulse test ; pulse width $\leq 300 \mu s$, duty cycle $\leq 2\%$.

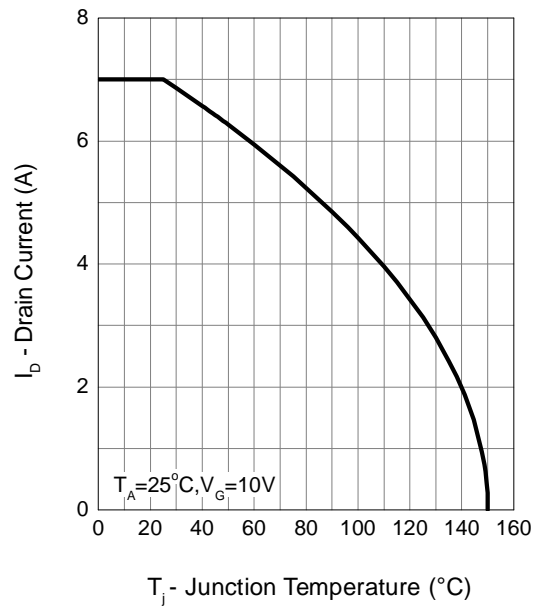
Note e : Guaranteed by design, not subject to production testing.

Typical Operating Characteristics

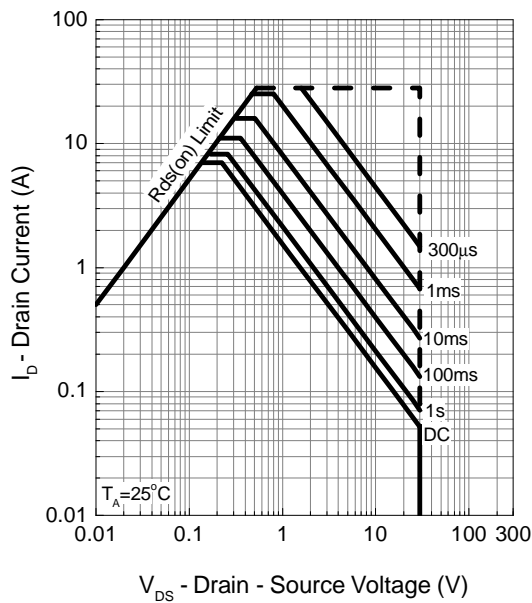
Power Dissipation



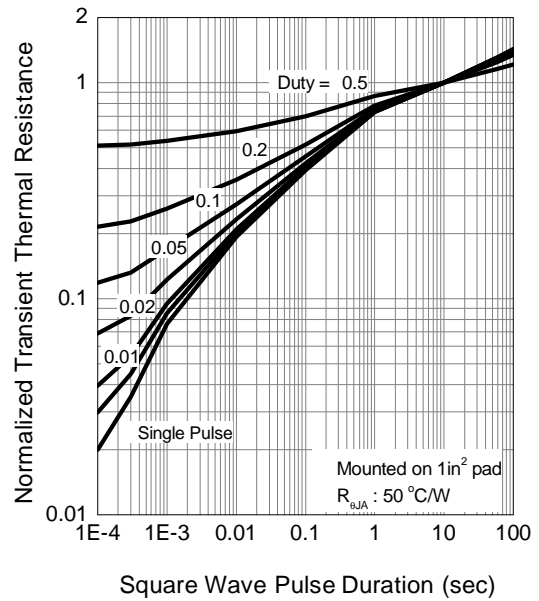
Drain Current



Safe Operation Area

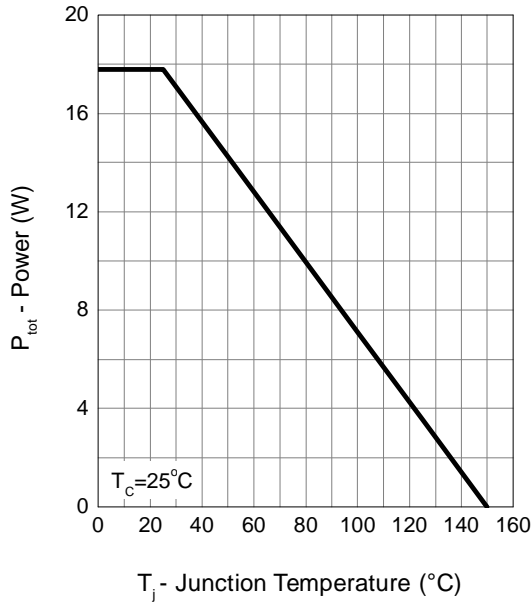


Thermal Transient Impedance

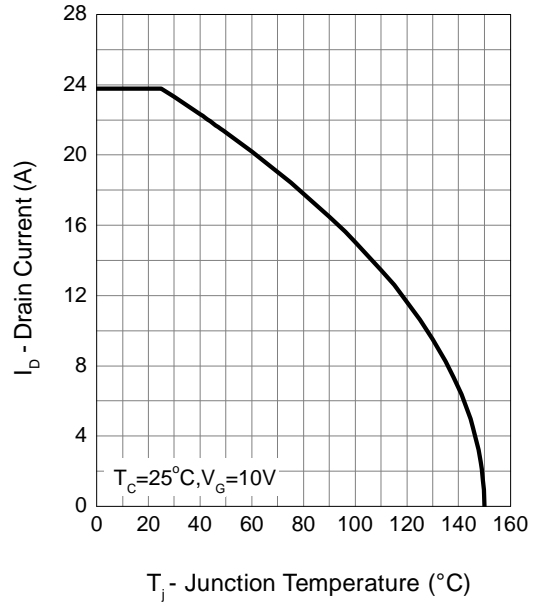


Typical Operating Characteristics (Cont.)

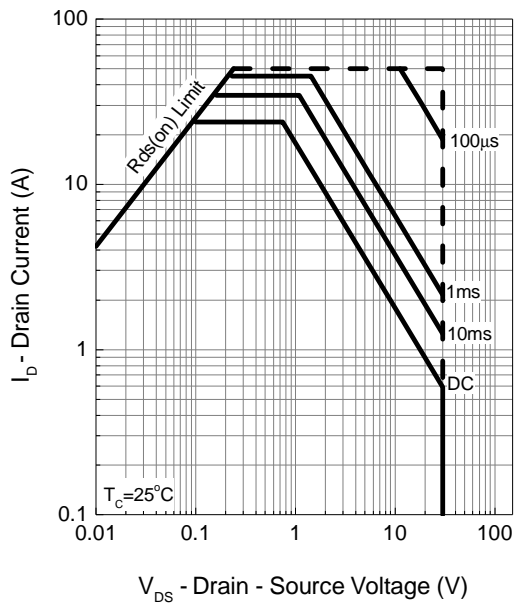
Power Dissipation



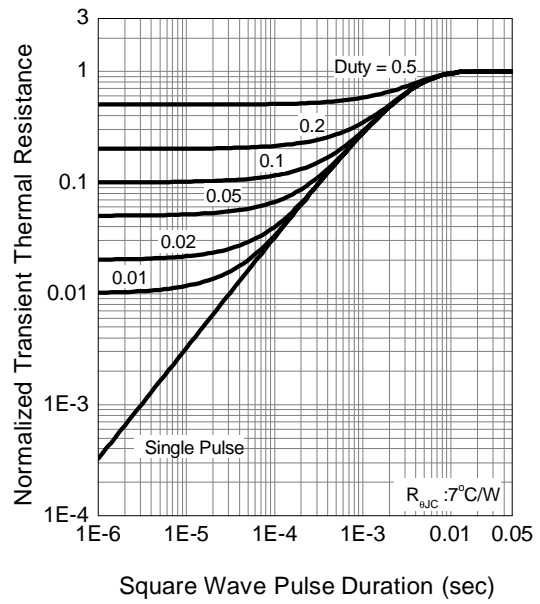
Drain Current



Safe Operation Area

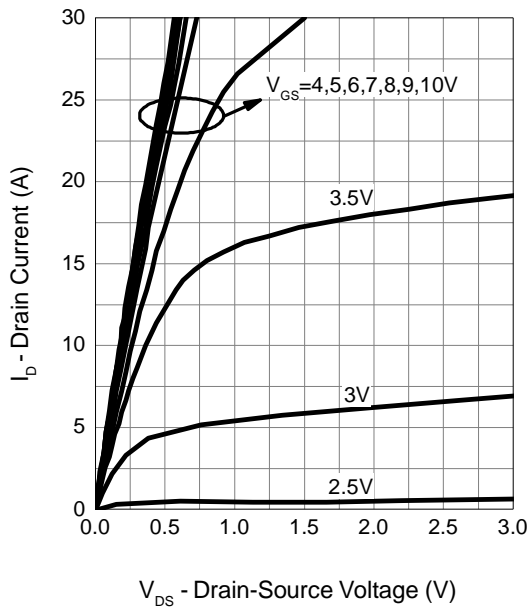


Thermal Transient Impedance

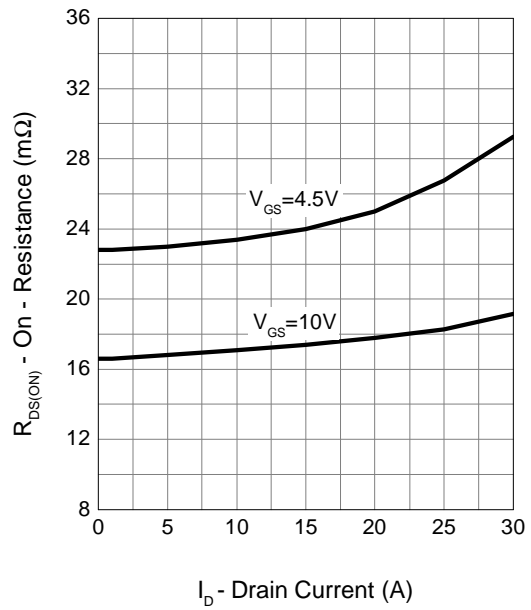


Typical Operating Characteristics (Cont.)

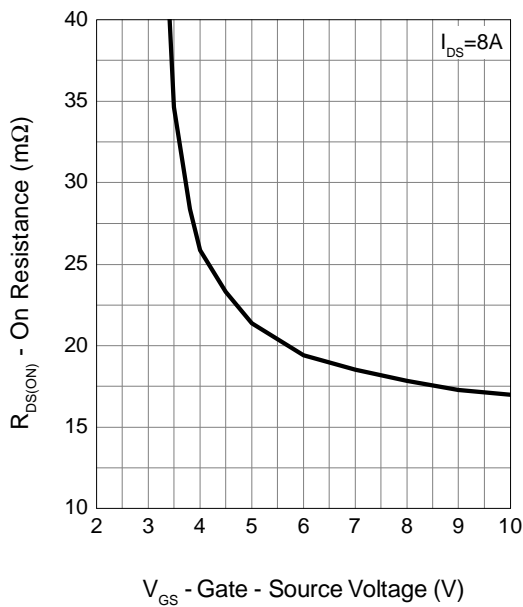
Output Characteristics



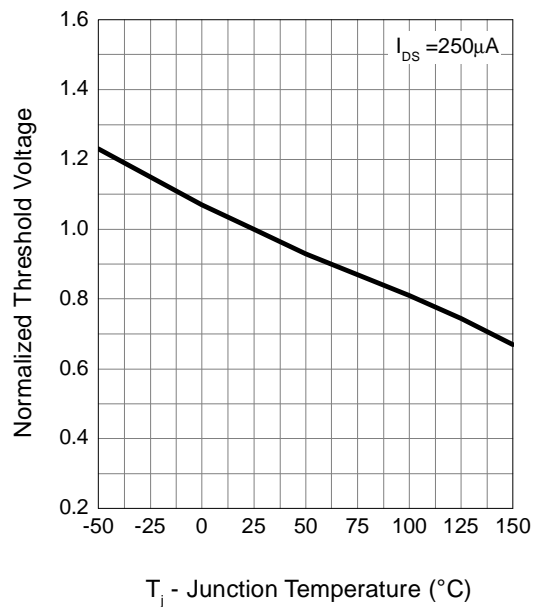
Drain-Source On Resistance



Gate-Source On Resistance

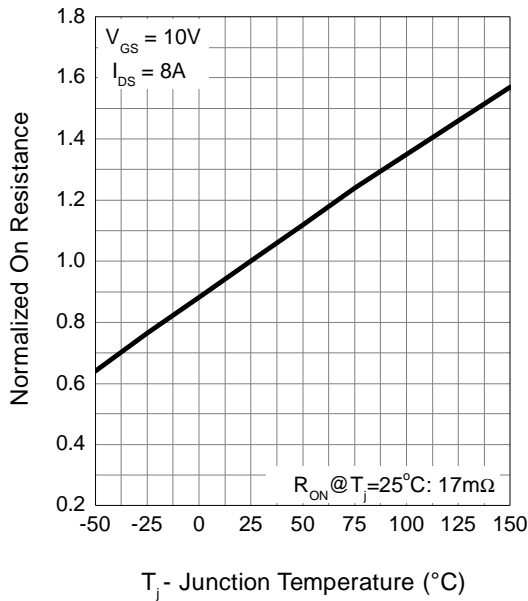


Gate Threshold Voltage

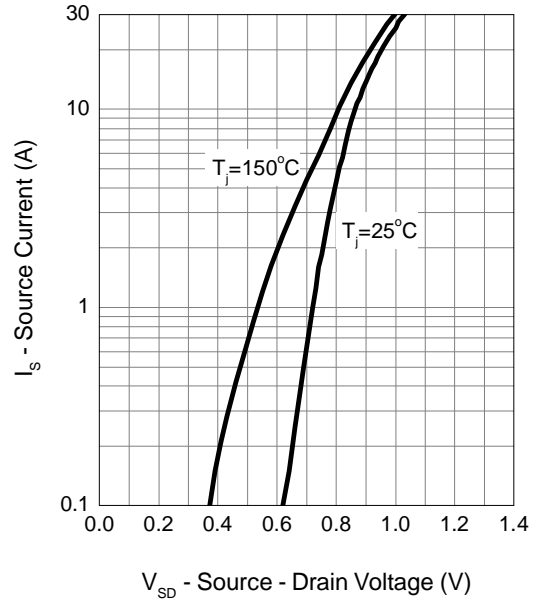


Typical Operating Characteristics (Cont.)

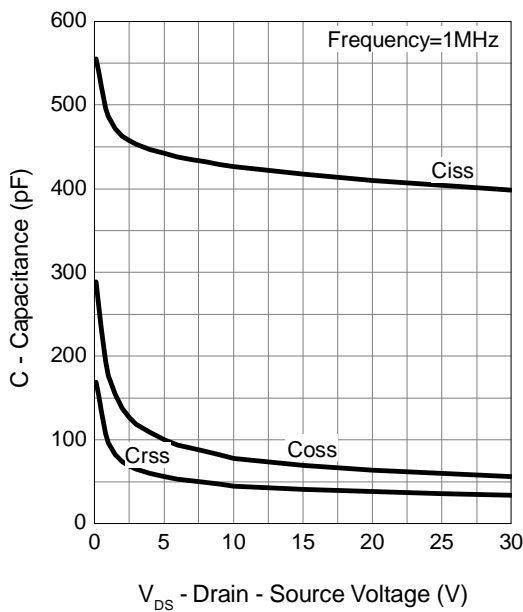
Drain-Source On Resistance



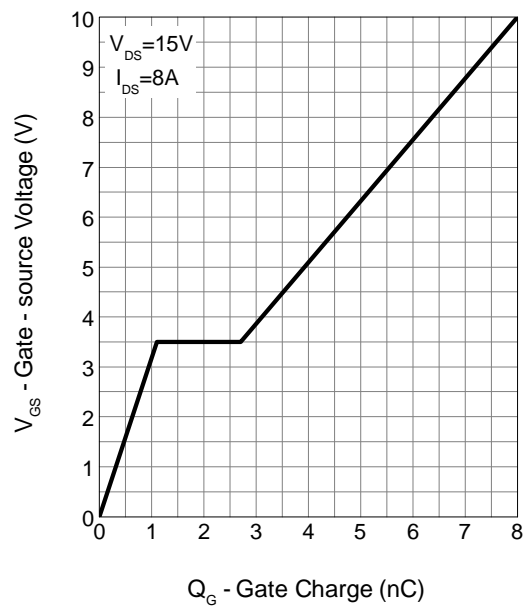
Source-Drain Diode Forward



Capacitance

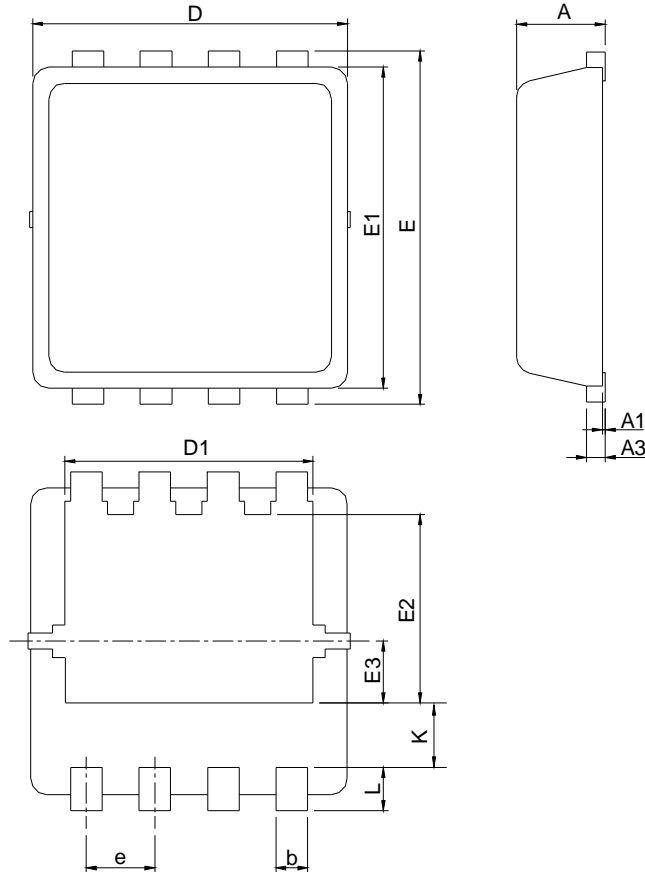


Gate Charge



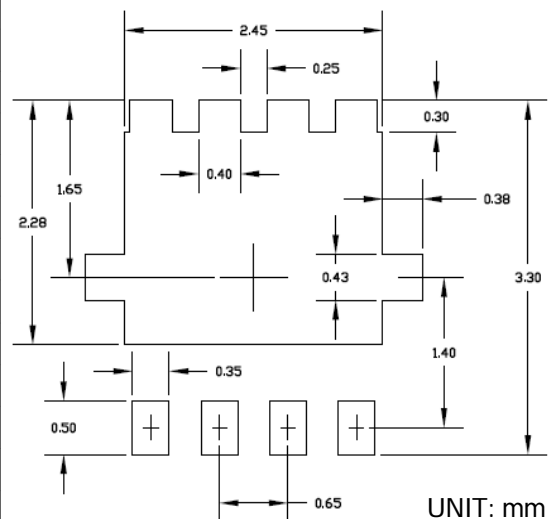
Package Information

DFN3x3-8



SYMBOL	DFN3x3-8			
	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	0.80	1.00	0.031	0.039
A1	0.00	0.05	0.000	0.002
A3	0.10	0.25	0.004	0.010
b	0.24	0.35	0.009	0.014
D	2.90	3.10	0.114	0.122
D1	2.25	2.45	0.089	0.096
E	3.10	3.30	0.122	0.130
E1	2.90	3.10	0.114	0.122
E2	1.65	1.85	0.065	0.073
E3	0.56	0.58	0.022	0.023
e	0.65 BSC		0.026 BSC	
K	0.475	0.775	0.019	0.031
L	0.30	0.50	0.012	0.020

RECOMMENDED LAND PATTERN



Flow (wave) soldering (solder dipping)

Product	Peak Temperature	Dipping Time
Pb device	245°C ±5°C	5sec ±1 sec
Pb-Free device	260°C +0/-5°C	5sec ±1 sec



This integrated circuit can be damaged by ESD. UniverChip Corporation recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedure can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

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